

MGBR40S45C

Preliminary

DIODE

DUAL MOS GATED BARRIER RECTIFIER

DESCRIPTION

The UTC **MGBR40S45C** is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

FEATURES

* Super low forward voltage drop * High switching speed



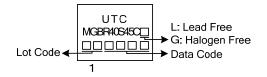
ORDERING INFORMATION

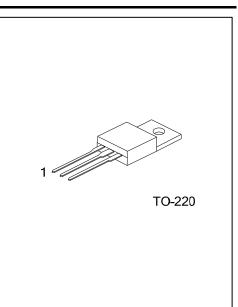
Ordering Number		Daakaga	Pin Assignment			Packing	
Lead Free	Halogen Free	Package	1	2	3	Facking	
MGBR40S45CL-TA3-T	MGBR40S45CG-TA3-T	TO-220	Α	К	А	Tube	

Note: Pin Assignment: A: Anode K: Cathode

MGBR40S45CL-TA3-T	(1)Packing Type	(1) T: Tube
	(2)Package Type	(2) TA3: TO-220
	(3)Green Package	(3) L: Lead Free, G: Halogen Free and Lead Free

MARKING





■ ABSOLUTE MAXIMUM RATINGS (PER LEG) (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Tor capacitance load, derate carrent by 2	0 /0.				
PARAMETER		SYMBOL	RATINGS	UNIT	
DC Blocking Voltage		V _{RM}	45	V	
Working Peak Reverse Voltage		V _{RWM}	45	V	
Peak Repetitive Reverse Voltage		V _{RRM}	45	V	
Average Rectified Output Current Per	Per Leg		20	А	
Device	Total	IO	40	А	
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I _{FSM}	350	А	
Operating Junction Temperature		TJ	-65~+150	°C	
Storage Temperature		T _{STG}	-65~+150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL CHARACTERISTICS (PER LEG)

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Case	θ _{JC}	2	°C/W

■ ELECTRICAL CHARACTERISTICS (PER LEG) (T_A =25°C unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	I _R =0.50mA	45			V
Forward Voltage Drop	VEM	I _F =20A, T _J =25°C			0.50	V
		I _F =20A, T _J =125°C			0.45	V
Leakage Current (Note 1)	RM	V _R =45V, T _J =25°C			500	μA
		V _R =45V, T _J =125°C			100	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.

